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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR 2SJ602

SWITCHING P-CHANNEL POWER MOS FET

DESCRIPTION

The 2SJ602 is P-channel MOS Field Effect Transistor designed for solenoid, motor and lamp driver.

FEATURES

• Super low on-state resistance:

 $R_{DS(on)1}=73~m\Omega~MAX.~(V_{GS}=-10~V,~I_{D}=-10~A)$ $R_{DS(on)2}=107~m\Omega~MAX.~(V_{GS}=-4.0~V,~I_{D}=-10~A)$

• Low input capacitance:

 $C_{iss} = 1300 \text{ pF TYP.} (V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V})$

Built-in gate protection diode

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SJ602	TO-220AB
2SJ602-S	TO-262
2SJ602-ZJ	TO-263
2SJ602-Z	TO-220SMD Note

Note TO-220SMD package is produced only in Japan

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	-60	V
Gate to Source Voltage (Vps = 0 V)	Vgss	∓20	V
Drain Current (DC) (Tc = 25°C)	I _{D(DC)}	∓20	Α
Drain Current (pulse) Note1	ID(pulse)	∓50	Α
Total Power Dissipation (Tc = 25°C)	PT	40	W
Total Power Dissipation (T _A = 25°C)	PT	1.5	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	-20	Α
Single Avalanche Energy Note2	Eas	40	mJ

Notes 1. PW \leq 10 μ s, Duty cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = -30 V, R_G = 25 Ω , V_{GS} = $-20 \rightarrow 0$ V

(TO-220AB)



(TO-262)



(TO-263, TO-220SMD)



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ELECTRICAL CHARACTERISTICS (TA = 25°C)

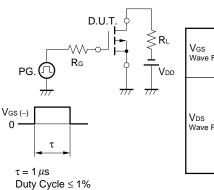
	•	· · · · · · · · · · · · · · · · · · ·				
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	Vps = -60 V, Vgs = 0 V			-10	μΑ
Gate Leakage Current	Igss	$V_{GS} = \mp 20 \text{ V}, V_{DS} = 0 \text{ V}$			∓10	μΑ
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = -10 V, I _D = -1 mA	-1.5	-2.0	-2.5	V
Forward Transfer Admittance	yfs	V _{DS} = -10 V, I _D = -10 A	8	16		S
Drain to Source On-state Resistance	RDS(on)1	Vgs = -10 V, ID = -10 A		59	73	mΩ
	RDS(on)2	Vgs = -4.0 V, ID = -10 A		75	107	mΩ
Input Capacitance	Ciss	Vps = -10 V		1300		pF
Output Capacitance	Coss	V _G s = 0 V		240		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		100		pF
Turn-on Delay Time	td(on)	$V_{DD} = -30 \text{ V}, \text{ ID} = -10 \text{ A}$		9		ns
Rise Time	t r	V _G S = −10 V		12		ns
Turn-off Delay Time	td(off)	$R_G = 0 \Omega$		54		ns
Fall Time	t f			15		ns
Total Gate Charge	Q _G	V _{DD} = -48 V		26		nC
Gate to Source Charge	Qgs	V _G S = −10 V		5		nC
Gate to Drain Charge	Q _{GD}	I _D = -20 A		7		nC
Body Diode Forward Voltage	V _{F(S-D)}	IF = 20 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 20 A, VGS = 0 V		50		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ μs		110		nC

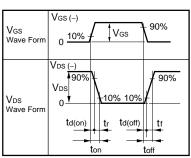
TEST CIRCUIT 1 AVALANCHE CAPABILITY

$V_{GS} = -20 \rightarrow 0 \text{ V}$ $V_{GS} = -20 \rightarrow 0 \text{ V}$ V_{DS} V_{DS} V_{DS} V_{DS}

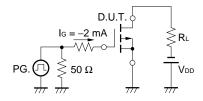
Starting Tch

TEST CIRCUIT 2 SWITCHING TIME



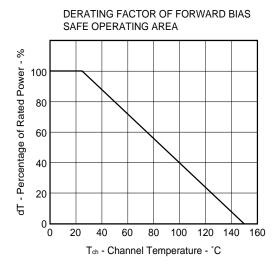


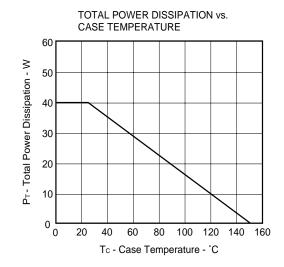
TEST CIRCUIT 3 GATE CHARGE



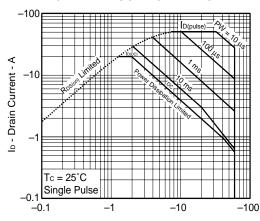


TYPICAL CHARACTERISTICS (TA = 25°C)



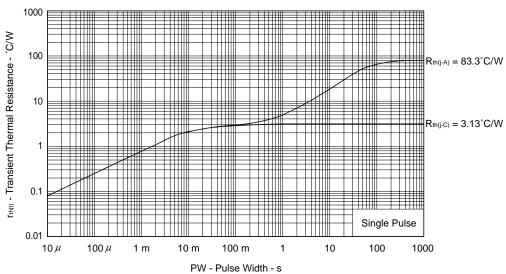


FORWARD BIAS SAFE OPERATING AREA

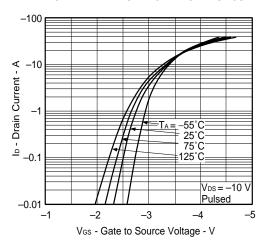


V_{DS} - Drain to Source Voltage - V

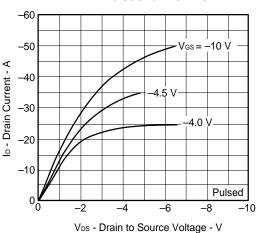
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



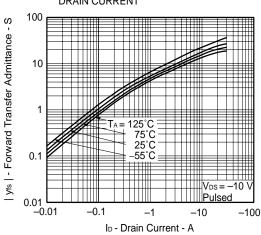
FORWARD TRANSFER CHARACTERISTICS



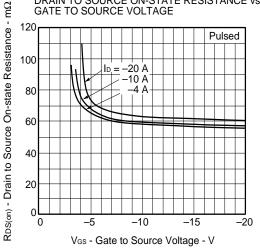
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



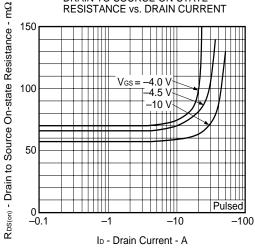
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



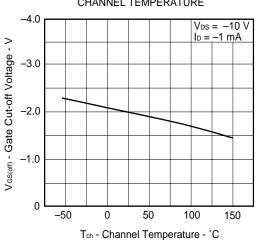
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



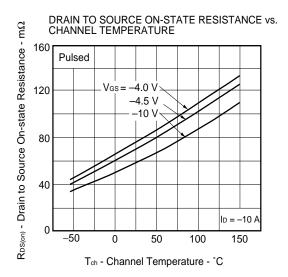
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

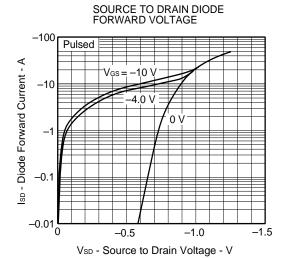


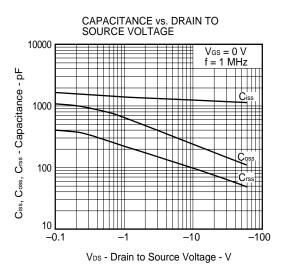
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE

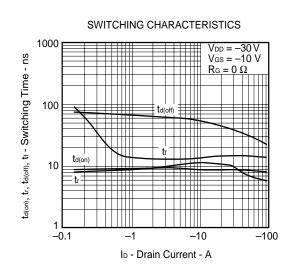


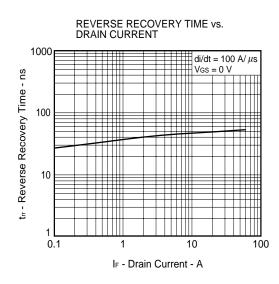


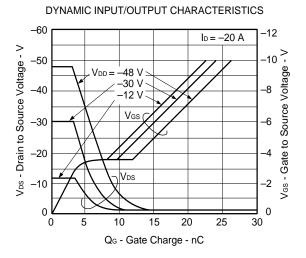


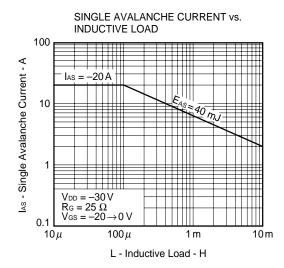


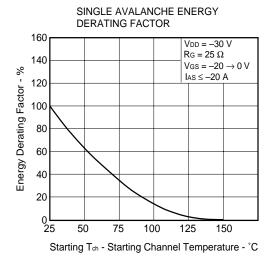






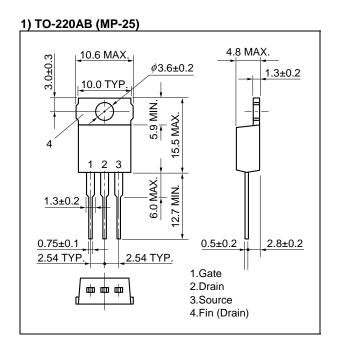


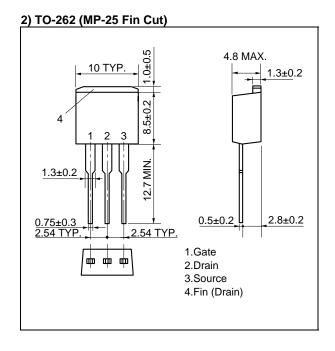


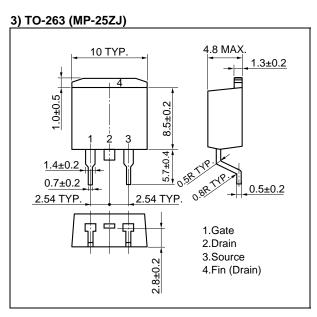


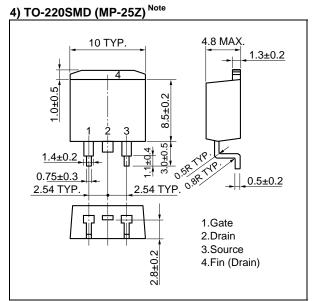


★ PACKAGE DRAWINGS (Unit: mm)



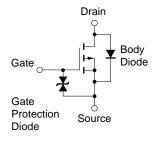






Note This package is produced only in Japan.

EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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